



Product Specifications

PART NO:

VL366S6553-GAS/GHS/GLS

REV:

1.5

General Information

512MB 64Mx64 SDRAM PC100/PC133 UNBUFFERED 168 PIN DIMM

Description: The VL366S6553 is a 64M x 64 Synchronous Dynamic RAM high density memory module. This memory module consists of 16 CMOS 32Mx8 bits with 4 banks Synchronous DRAMs in TSOP-II 400 mil packages and a 2K EEPROM in 8-pin TSSOP package. This module is a 168-pin Dual In-line Memory Module and is intended for mounting into connector sockets. Decoupling capacitors are mounted on the printed circuit board for each SDRAM.

Features:

- Unbuffered 8 byte SDRAM 168pin DIMM
- High Speed - 100MHz, 133MHz, CL2, CL3
- Burst Mode Operation
- Auto & Self refresh Capability (8192 Cycles/64ms)
- LVTTTL compatible inputs and outputs
- Single 3.3V ± 0.3 V power supply
- 13/10/4 Addressing (Row/Column/Bank)
- MRS cycle with address key programs
- EPROM Serial Presence Detect
- Gold (Au) contacts
- Lead-free/RoHS compliant
- PCB height: **1150 (mil)**, single sided component

Pin Name	Function
A0-A12	Address inputs
BA0, BA1	Bank Select Address
DQ0-DQ63	Data Input/Output
CLK0, CLK1, CLK2, CLK3	Clock Input
CKE0, CKE1	Clock Enable Input
CS0#~CS3#	Chip Select Input
RAS#	Row Address Strobe
CAS#	Column Address Input
WE#	Write Enable
DQM0-DQM7	Data input/output mask
VDD	Power Supply (3.3V)
VSS	Ground
*VREF	Power Supply for Reference
SDA	Serial Data Input/Output
SCL	SPD Clock Input
SA0~SA2	Address in EEPROM
NC	No Connect

* These pins are not used in this module.

Order Information:

VL366S6553-GA S X

DRAM DIE (Option)

DRAM MANUFACTURER
S - SAMSUNG

MODULE SPEED
GA: PC133 @ CL3
GH: PC100 @ CL2
GL: PC100 @ CL3

VL: Lead-free/RoHS



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Pin Configuration

Pin Number	Front Side
1	V _{SS}
2	DQ0
3	DQ1
4	DQ2
5	DQ3
6	V _{DD}
7	DQ4
8	DQ5
9	DQ6
10	DQ7
11	DQ8
12	V _{SS}
13	DQ9
14	DQ10
15	DQ11
16	DQ12
17	DQ13
18	V _{DD}
19	DQ14
20	DQ15
21	NC
22	NC
23	V _{SS}
24	NC
25	NC
26	V _{DD}
27	WE#
28	DQM0
29	DQM1
30	CS0#
31	NC
32	V _{SS}
33	A0
34	A2
35	A4
36	A6
37	A8
38	A10/AP
39	BA1
40	V _{DD}
41	V _{DD}
42	CLK0

Pin Number	Front Side
43	V _{SS}
44	NC
45	CS2#
46	DQM2
47	DQM3
48	NC
49	V _{DD}
50	NC
51	NC
52	NC
53	NC
54	V _{SS}
55	DQ16
56	DQ17
57	DQ18
58	DQ19
59	V _{DD}
60	DQ20
61	NC
62	NC
63	CKE1
64	V _{SS}
65	DQ21
66	DQ22
67	DQ23
68	V _{SS}
69	DQ24
70	DQ25
71	DQ26
72	DQ27
73	V _{DD}
74	DQ28
75	DQ29
76	DQ30
77	DQ31
78	V _{SS}
79	CLK2
80	NC
81	WP
82	SDA
83	SCL
84	V _{DD}

Pin Number	Back Side
85	V _{SS}
86	DQ32
87	DQ33
88	DQ34
89	DQ35
90	V _{DD}
91	DQ36
92	DQ37
93	DQ38
94	DQ39
95	DQ40
96	V _{SS}
97	DQ41
98	DQ42
99	DQ43
100	DQ44
101	DQ45
102	V _{DD}
103	DQ46
104	DQ47
105	NC
106	NC
107	V _{SS}
108	NC
109	NC
110	V _{DD}
111	CAS#
112	DQM4
113	DQM5
114	CS1#
115	RAS#
116	V _{SS}
117	A1
118	A3
119	A5
120	A7
121	A9
122	BA0
123	A11
124	V _{DD}
125	CLK1
126	A12

Pin Number	Back Side
127	V _{SS}
128	CKE0
129	CS3#
130	DQM6
131	DQM7
132	NC
133	V _{DD}
134	NC
135	NC
136	NC
137	NC
138	V _{SS}
139	DQ48
140	DQ49
141	DQ50
142	DQ51
143	V _{DD}
144	DQ52
145	NC
146	NC
147	NC
148	V _{SS}
149	DQ53
150	DQ54
151	DQ55
152	V _{SS}
153	DQ56
154	DQ57
155	DQ58
156	DQ59
157	V _{DD}
158	DQ60
159	DQ61
160	DQ62
161	DQ63
162	V _{SS}
163	CLK3
164	NC
165	SA0
166	SA1
167	SA2
168	V _{DD}



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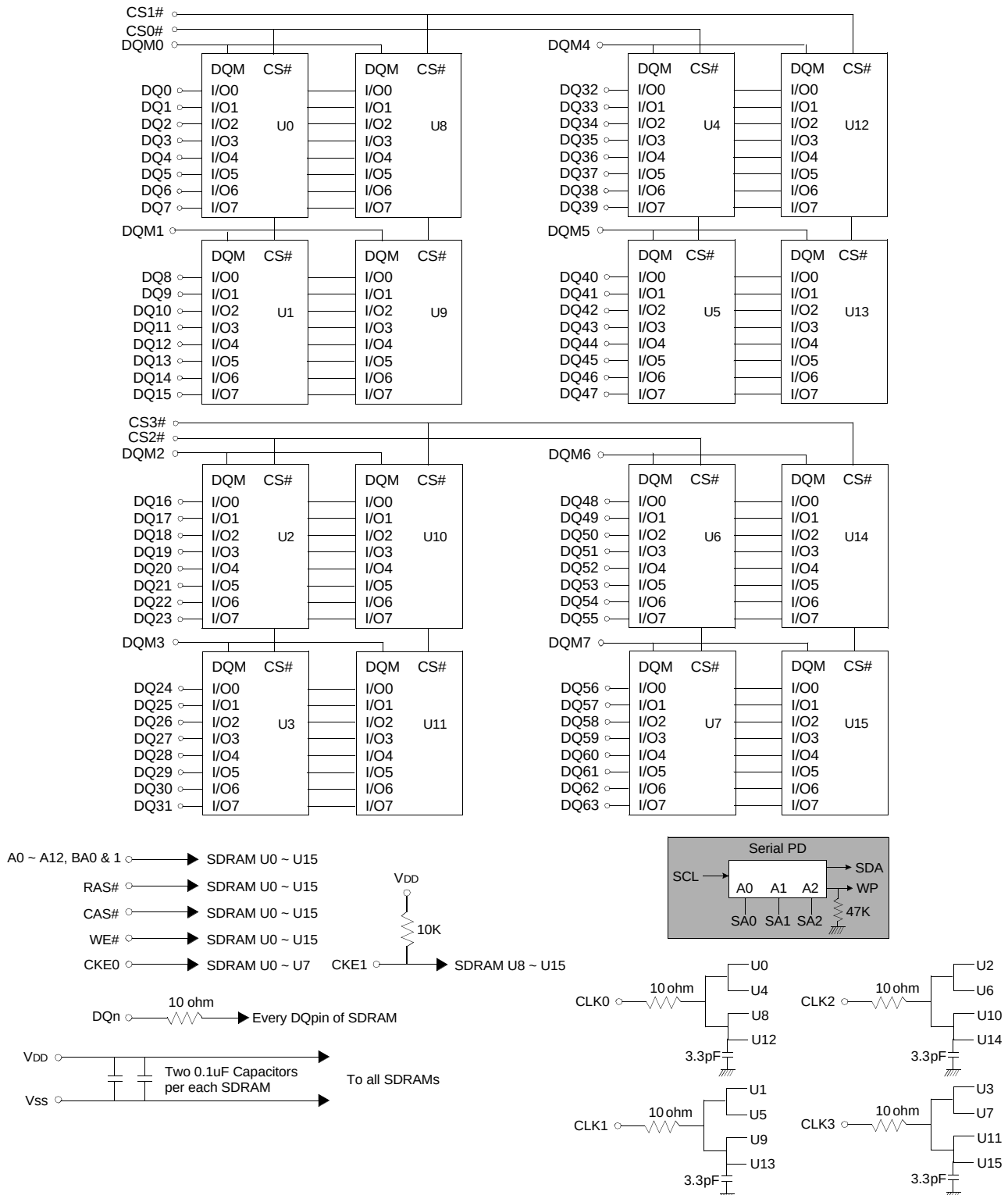
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Functional Block Diagram



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Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Voltage on any pin relative to Vss	V _{IN} , V _{OUT}	-1.0 ~ 4.6	V
Voltage on VDD supply relative to Vss	VDD, VDDQ	-1.0 ~ 4.6	V
Storage temperature	T _{STG}	-55 ~ +150	°C
Power dissipation	P _D	16	W
Short circuit current	I _{OS}	50	mA
Note: Permanent device damage may occur if "ABSOLUTE MAXIMUM RATINGS" are exceeded. Functional operation should be restricted to recommended operating condition. Exposure to higher than recommended voltage for extended periods of time could affect device reliability.			

Recommended DC Operating Conditions (T_A = 0°C to +70°C)

Parameter	Symbol	Min	Typ	Max	Unit	Note
Supply voltage	VDD, VDDQ	3.0	3.3	3.6	V	
Input high voltage	V _{IH}	2.0	3.0	VDDQ+0.3	V	1
Input low voltage	V _{IL}	-0.3	0	0.8	V	2
Output high voltage	V _{OH}	2.4	-	-	V	I _{OH} = -2mA
Output low voltage	V _{OL}	-	-	0.4	V	I _{OL} = 2mA
Input leakage current (Inputs)	I _{IL}	-10	-	10	uA	3
Input leakage current (I/O pins)	I _{IL}	-3	-	3	uA	3,4
Notes: 1. V _{IH} (max) = 5.6V AC. The overshoot voltage duration is <= 3ns. 2. V _{IL} (min) = 2.0V AC. The undershoot voltage duration is <= 3ns. 3. Any input 0V <= V _{IN} <= VDDQ. 4. DOUT is disabled, 0V <= V _{OUT} <= VDDQ.						

Capacitance (T_A = 25°C, f = 1MHz, VDD = 3.3V)

Parameter	Symbol	Min	Max	Unit
Input capacitance (A0 ~ A12, BA0 ~ BA1)	C _{IN1}	80	100	pF
Input capacitance (RAS#, CAS#, WE#)	C _{IN2}	80	100	pF
Input capacitance (CKE0, CKE1)	C _{IN3}	50	60	pF
Input capacitance (CLK0 ~ CLK3)	C _{IN4}	40	45	pF
Input capacitance (CS0# ~ CS3#)	C _{IN5}	25	35	pF
Input capacitance (DQM0 ~ DQM7)	C _{IN6}	15	20	pF
Data input/output capacitance (DQ0 ~ DQ63)	C _{OUT}	10	15	pF

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DC Characteristics

(Recommended operation condition unless otherwise noted, TA = 0°C to +70°C)

Parameter	Symbol	Test Condon	Version			Unit	Note
			-GA	-GH	-GL		
Operating current (One bank active)	Icc1	Burst length = 1 trc >= trc(min) IoL = 0 mA	960	960	960	mA	1
Precharge standby current in power-down mode	Icc2P	CKE <= VIL(max), tcc = 10ns	32			mA	
	Icc2PS	CKE & CLK <=VIL(max), tcc = 00	32			mA	
Precharge standby current in non power-down mode	Icc2N	CKE >= VIH (min), CS# >= VIH (min), tcc = 10ns Input signals are changed one time during 20ns	320			mA	
	Icc2NS	CKE >= VIH(min), CLK <= VIL(max), tcc = 00 Input signals are stable	160			mA	
Active standby current in power- down mode	Icc3P	CKE <= VIL(max), tcc = 10ns	96			mA	
	Icc3PS	CKE & CLK <= VIL(max), tcc = 00	96			mA	
Active standby current in non power-down mode (One bank active)	Icc3N	CKE >= VIH(min), CS# >= VIH(min), tcc = 10ns Input signals are changed one time during 20ns	480			mA	
	Icc3NS	CKE >= VIH(min), CLK <= VIL (max), tcc = 00 Input signals are stable	400			mA	
Operating current (Burst mode)	Icc4	IoL = 0 mA Page burst 2 Banks actived tccd = 2CLKs	1120	1040	1040	mA	1
Refresh current	Icc5	trc >= trc(min)	1840	1760	1760	mA	2
Self refresh current	Icc6	CKE <= 0.2V	48			mA	
Note: 1. Measured with outputs open. 2.Refresh period is 64ms.							



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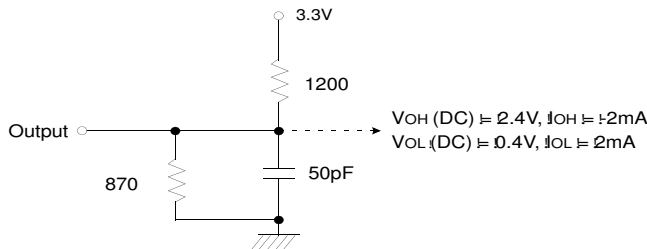
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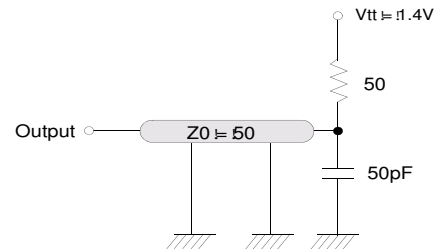
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AC Operating Test Conditions (VDD = 3.3V, TA = 0°C to +70°C)

Parameter	Value	Unit
AC input levels (V _H /V _L)	2.4/0.4	V
Input timing measurement reference level	1.4	V
Input rise and fall time	tr/tf = 1/1	ns
Output timing measurement reference level	1.4	V
Output load condition	See Fig.2	



(Fig. 1) DC output load circuit !



(Fig. 2) AC output load circuit !

Operating AC Parameter

Parameter	Symbol	Version			Unit	Note
		-GA	-GH	-GL		
Row active to row active delay	t _{RRD} (min)	15	20	20	ns	1
RAS# to CAS# delay	t _{RCD} (min)	20	20	20	ns	1
Row precharge time	t _{RP} (min)	20	20	20	ns	1
Row active time	t _{RAS} (min)	45	50	50	ns	1
	t _{RAS} (max)	100			us	
Row cycle time	t _{RC} (min)	65	70	70	ns	1
Last data in to row precharge	t _{RDL} (min)	2			CLK	2
Last data in to Active delay	t _{DAL} (min)	2 CLK + t _{RP}			-	
Last data in to new col. address delay	t _{CdL} (min)	1			CLK	1
Last data in to burst stop	t _{BDL} (min)	1			CLK	2
Col. address to col. address delay	t _{CCD} (min)	1			CLK	2
Number of valid output data	CAS Latency = 3	2			CLK	3
	CAS Latency = 2	1			ea	4

Notes: 1. The minimum number of clock cycles is determined by dividing the minimum time required with clock cycle time and then rounding off to the next higher integer.
2. Minimum delay is required to complete write.
3. All parts allow every cycle column address change.
4. In case of row precharge interrupt, auto precharge and read burst stop.

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Operating AC Parameter

Parameter		Symbol	-GA		-GH		-GL		Unit	Note
			Min	Max	Min	Max	Min	Max		
CLK cycle time	CAS latency = 3	tCC	7.5	1000	-	1000	10	1000	ns	1
	CAS latency = 2		-		10		-			
CLK to valid output delay	CAS latency = 3	tSAC		5.4		-		6	ns	1,2
	CAS latency = 2			-		6		-		
Output data hold time	CAS latency = 3	tOH	3		-		3		ns	2
	CAS latency = 2		-		3		-			
CLK high pulse width		tCH	2.5		3		3		ns	3
CLK low pulse width		tCL	2.5		3		3		ns	3
Input setup time		tSS	1.5		2		2		ns	3
Input hold time		tSH	0.8		1		1		ns	3
CLK to output in Low-Z		tSLZ	1		1		1		ns	2
CLK to output in Hi-z	CAS latency = 3	tSHZ		5.4		-		6	ns	
	CAS latency = 2			-		6		-		

Notes: 1. Parameters depend on programmed CAS latency.
 2. If clock rising time is longer than 1ns, $(tr/2-0.5)ns$ should be added to the parameter.
 3. Assumed input rise and fall time $(tr \& \; tf) = 1ns$.
 if $tr \& \; tf$ is longer than 1ns, transient time compensation should be considered,
 i.e. $[(tr + tf)/2-1]ns$ should be added to the parameter.

